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Docket No.: T2171.0180/P180 (PATENT)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Takahisa Yamaha

Allowed: June 25, 2004

Application No.: 09/518,709

Confirmation No.: 5749

Filed: March 3, 2000

Art Unit: 2815

For: MANUFACTURE METHOD FOR

SEMICONDUCTOR WITH SMALL VARIATION IN MOS THRESHOLD

VOLTAGE

Examiner: E. Ortiz

REQUEST FOR SUPPLEMENTAL NOTICE OF ALLOWANCE

Attn: MS Issue Fee Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

Applicants received a Notice of Allowance dated June 25, 2004.

On March 12, 2001, Applicant filed a Information Disclosure Statement. During final review of the allowed application, Applicant note that the Information Disclosure Statement of March 12, 2001 was not acknowledged.

Applicant respectfully requests that the Information Disclosure Statement dated March 12, 2001 be acknowledged and considered for the above-referenced patent application, before payment of the issue fee. A copy of said Information Disclosure Statement, Applicant's Art Citation, References submitted on 03/12/2001 (plus stamped postcard indicating receipt by the U.S. Patent Office) are enclosed for your convenience.

Application No.: 09/518,709 Docket No.: T2171.0180/P180

Please charge any credits or deficiencies to our Deposit Account No. 50-2215.

Dated: August 3, 2004

Respectfully submitted,

Steven I. Weisburd

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